L Number	Hits	Search Text	DB	Time stamp
1	84852	dielectric adj (layer or film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 07:58
2	415	(dielectric adj (layer or film)) and ((dielectric adj constant) same (convers$3 or convert$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 10:23
3	299	((dielectric adj (layer or film)) and ((dielectric adj constant) same (convers$3 or convert$3))) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 08:07
4	169	(((dielectric adj (layer or film)) and ((dielectric adj constant) same (convers$3 or convert$3))) and semiconductor) and ("438")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 08:07
5	87	(dielectric adj (layer or film)) and ((first adj dielectric adj constant) same (second adj dielectric adj constant))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 08:25
6	2	(dielectric adj (layer or film)) and ((dielectric adj constant) same ((convers$3 or convert$3) adj (dielectric adj constant)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 10:24
-	394	(438/240).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:29
-	204	(438/243).CCLS.	USPAT; EPO; JPO; DERWENT	2002/05/21 14:04
-	83	(438/246).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	37	(438/247).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	218	(438/386).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	84	(438/387).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	55	(438/389).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	28	(438/390).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/09 11:10
-	107	(438/244).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/16 15:23
-	2	(cover$3 adj3 (first adj1 area)) and (first adj1 dielectric)	USPAT	2001/11/16 15:28
-	2	((cover$3 adj3 (first adj1 area)) and (first adj1 dielectric)) and (second adj1 dielectric)	USPAT	2001/11/16 15:29
-	155	cover$3 adj3 (first adj1 area)	USPAT	2001/11/19 08:46
-	155	cover$3 adj3 (first adj1 area)	USPAT	2001/11/19 08:49
-	5997	first adj1 dielectric	USPAT	2002/05/21 14:37
-	2	(first adj1 dielectric) and (cover$3 adj3 (first adj1 area))	USPAT	2001/11/19 08:50
-	217	first adj1 dielectric adj1 constant	USPAT	2001/11/19 08:51

-	0	((first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)) and ((E-beams) or (I-beams) or (amine))	USPAT	2001/11/19 08:54
-	0	((first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)) and (E-beams)	USPAT	2001/11/19 08:54
-	0	((first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)) and (I-beams)	USPAT	2001/11/19 08:54
-	0	((first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)) and (amine)	USPAT	2001/11/19 08:54
-	170	(first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)	USPAT	2001/11/19 09:16
-	1557	438/240,244,238,239,243,246,247,386,389,390	USPAT.cls.	2002/12/03 14:18
-	0	438/240,244,238,239,243,246,247,386,389,390 and (I-beams)	USPAT.cls.	2002/12/03 14:21
-	1	438/240,244,238,239,243,246,247,386,389,390 and (e-beams)	USPAT.cls.	2001/11/19 11:19
-	7	438/240,244,238,239,243,246,247,386,389,390 and (amine)	USPAT.cls.	2001/11/19 09:19
-	0	(438/240,244,238,239,243,246,247,386,389,390 and (amine)) and (first adj1 dielectric)	USPAT.ccls.	2001/11/19 09:24
-	0	(438/240,244,238,239,243,246,247,386,389,390 and (e-beams)) and (first adj1 dielectric)	USPAT.ccls.	2001/11/19 09:20
-	148	438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)	USPAT.cls.	2001/11/19 09:20
-	118	(438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)	USPAT.ccls.	2001/11/19 09:20
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (amine)	USPAT.ccls.	2001/11/19 09:21
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (E-beams)	USPAT.ccls.	2001/11/19 09:54
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (I-beams)	USPAT.ccls.	2001/11/19 09:21
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (I adj1 beams)	USPAT.ccls.	2001/11/19 09:21
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (E adj1 beams)	USPAT.ccls.	2001/11/19 09:21
-	0	(438/240,244,238,239,243,246,247,386,389,390 and (amine)) and (second adj1 dielectric adj1 constant)	USPAT.ccls.	2001/11/19 09:24
-	0	(438/240,244,238,239,243,246,247,386,389,390 and (amine)) and (first adj1 dielectric adj1 constant)	USPAT.ccls.	2001/11/19 09:24
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (Electron adj1 beams)	USPAT.ccls.	2002/05/21 14:38
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (Electronic adj1 beams)	USPAT.ccls.	2001/11/19 09:54
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (ions adj1 beams)	USPAT.ccls.	2001/11/19 09:55
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (hydrogen adj1 amine)	USPAT.ccls.	2001/11/19 09:56
-	0	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (hydrogen adj1 silsesquioxane)	USPAT.ccls.	2001/11/19 09:56
-	3	((438/240,244,238,239,243,246,247,386,389,390 and (first adj1 dielectric)) and (second adj1 dielectric)) and (oxygen adj1 plasma)	USPAT.ccls.	2001/11/19 10:11
-	1	("6110842").PN.	USPAT	2001/11/19 10:11
-	6	("4764248" | "4980307" | "5672521" | "5763922" | "5834351" | "5937310").PN.	USPAT	2001/11/19 10:12

-	1	("6309922").PN.	USPAT	2001/11/19 11:31
-	2	("5652173" | "5770509").PN.	USPAT	2001/11/19 11:20
-	1	("5928960").PN.	USPAT	2001/11/19 11:31
-	281	(438/386).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/21 14:07
-	31	(438/390).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/21 14:07
-	59	(438/389).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/21 14:16
-	43	(438/247).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/21 14:35
-	96	(438/246).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/21 14:51
-	113	(438/387).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/21 15:04
-	164	(438/244).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/21 15:11
-	281	(438/386).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 07:40
-	273	(438/243).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 08:12
-	2429	438/240,244,238,239,243,246,247,386,389,390.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:34
-	27	438/240,244,238,239,243,246,247,386,389,390.ccls. and (I-beams or E-beam)	USPAT	2002/12/03 14:22
-	31	438/240,244,238,239,243,246,247,386,389,390.ccls. and (I-beams or E-beam)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:22
-	2428	438/240,244,238,239,243,246,247,386,389,390.ccls.	USPAT; US-PGPUB	2002/12/03 14:47
-	84852	dielectric adj (layer or film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:55

–	13087	(dielectric adj (layer or film)) and (convers$3 or convert$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
–	7979	((dielectric adj (layer or film)) and (convers$3 or convert$3)) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
–	3203	(((dielectric adj (layer or film)) and (convers$3 or convert$3)) and semiconductor) and ("438")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
–	909	((((dielectric adj (layer or film)) and (convers$3 or convert$3)) and semiconductor) and ("438")) and (dielectric adj constant)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
–	84852	dielectric adj (layer or film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 07:57
–	13087	(dielectric adj (layer or film)) and (convers$3 or convert$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
–	7979	((dielectric adj (layer or film)) and (convers$3 or convert$3)) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
–	3203	(((dielectric adj (layer or film)) and (convers$3 or convert$3)) and semiconductor) and ("438")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
–	909	((((dielectric adj (layer or film)) and (convers$3 or convert$3)) and semiconductor) and ("438")) and (dielectric adj constant)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:57